

## 0.6Ω Dual SPDT Negative Signal Handing Analog Switch

### General Description

The ET5228HAM is an advanced CMOS analog switch fabricated in Sub-micron silicon gate CMOS technology. The part also features guaranteed Break Before Make (BBM) switching, assuring the switches never short the driver. The switches can handle negative signal down to -2.5V.

ET5228HAM is offered in a small QFN10L package and operates over an ambient temperature range of -40°C to +125°C.

### Features

- Low  $R_{ON}$  is typical 0.6Ω @  $V_{CC} = 3.3V$
- Single supply operation from 1.65V to 5.5V
- Full -2.5V to  $V_{CC}$  signal handling capability
- High off-channel isolation
- Very low standby current
- Very low distortion
- Break-Before-Make(BBM) switching
- High continuous current capability is ±300mA through each switch
- Automotive AEC-Q100 Grade 1 Qualified
- Package information:

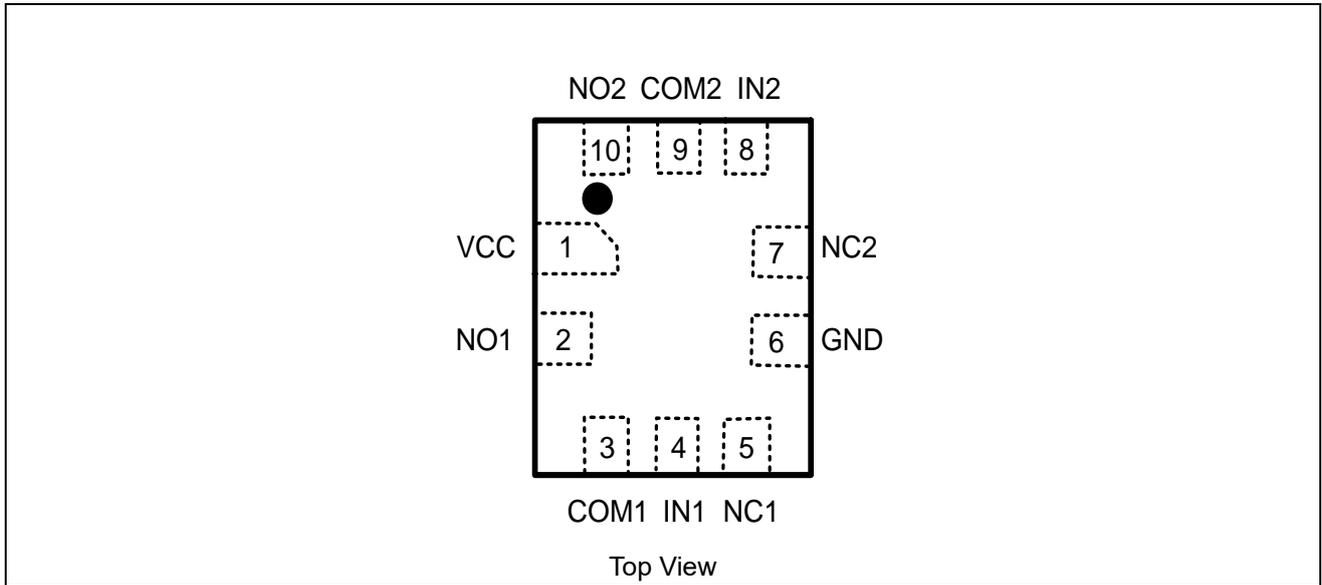
Part No.	Package	MSL
ET5228H	QFN10L (1.8mm×1.4mm)	Level 1

### Application

- Automotive device Audio Block/ Speaker
- Automotive device Amplifier Switching

# ET5228HAM

## Pin Configuration



## Pin Function

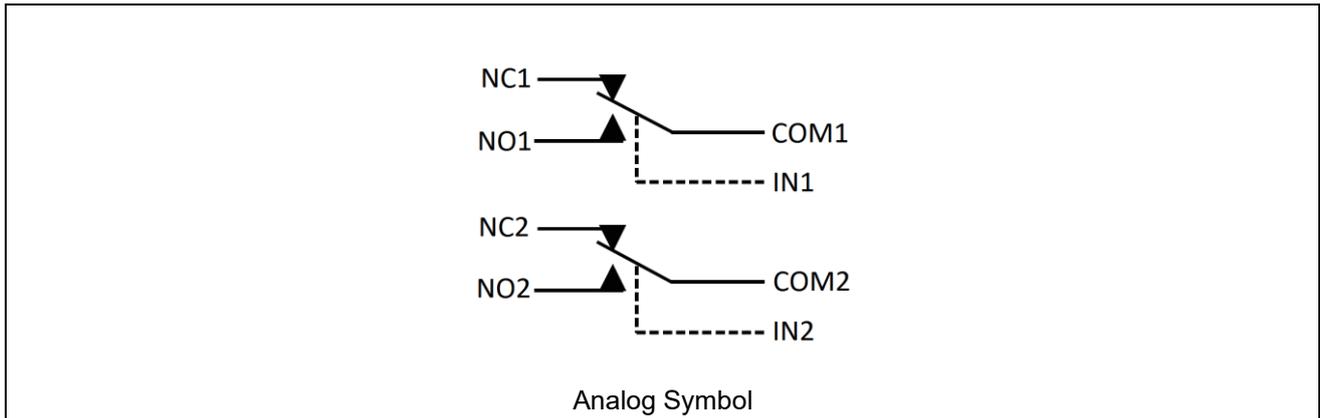
Pin NO.	Pin Name	Description
1	VCC	Power supply
2	NO1	Independent Channels
3	COM1	Common Channels
4	IN1	Controls
5	NC1	Independent Channels
6	GND	Ground (V)
7	NC2	Independent Channels
8	IN2	Controls
9	COM2	Common Channels
10	NO2	Independent Channels

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## Truth Table

IN1/2	NO1/2 to COM1/2	NC1/2 to COM1/2
0	OFF	ON
1	ON	OFF

## Analog Symbol



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## Absolute Maximum Ratings

Characteristic		Symbol	Value	Unit
Supply Voltage		$V_{CC}$	-0.5~+6.5	V
Analog Input Voltage		$V_{IS}$	-3~ $V_{CC}+0.3$ $ V_{CC}-V_{IS}  < 6.5V$	V
Digital Select Input Voltage		$V_{IN}$	-0.5~+6.5	V
Output Voltage		$V_O$	-3~ $V_{CC}+0.3$ $ V_{CC}-V_O  < 6.5V$	V
Continuous DC Current from COM to NC/NO		$I_{AN1}$	±300	mA
Peak Current from COM to NC/NO, 10 Duty Cycle <sup>(1)</sup>		$I_{AN-PK1}$	±500	mA
Continuous DC Current into COM/NO/NC with Respect to $V_{CC}$		$I_{CLMP}$	±100	mA
Maximum Junction Temperature		$T_{J(MAX)}$	150	°C
Storage Temperature		$T_S$	-55 to 150	°C
ESD	Human Body Model <sup>(2)</sup>	HBM	±6000	V
	Charge-Device Mode <sup>(2)</sup>	CDM	±1500	V
Latch Up (Current Maximum Rating) <sup>(2)</sup>		$I_{LU}$	±200	mA

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

**Note1.** Defined as 10% ON, 90% off duty cycle.

**Note2.** This device series incorporates ESD protection and is tested by the following methods:

HBM tested per AEC-Q100-002(EIA/JESD22-A114) ;

CDM tested per AEC-Q100-011(EIA/JESD22-C101);

Latch up Current Maximum Rating tested per AEC-Q100-004(EIA/JESD78E).

## Thermal Characteristics

Symbol	Package	Ratings	Value	Unit
$R_{\theta JA}$	QFN10L	Thermal Characteristics, Thermal Resistance, Junction-to-Air		°C/W

## Recommended Operating Conditions

Characteristic	Symbol	Min	Max	Unit
DC Supply Voltage	$V_{CC}$	1.65	5.5	V
Digital Select Input Voltage	$V_{IN}$	GND	5.5	V
Analog Input Voltage <sup>(3)</sup>	$V_{IS}$	-2.5	$V_{CC}$	V
Operating Temperature Range	$T_A$	-40	+125	°C
Input Rise or Fall Time, SELECT	$t_r, t_f$	0	20	ns/V

**Note3.** To ensure normal transmission of  $V_{IS}$ , please follow  $|V_{CC}-V_{IS}| < 5.5V$ .

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## Electrical Characteristics

Symbol	Parameter	Test Conditions	T <sub>A</sub> =25°C			T <sub>A</sub> =-40~125°C		Unit
			Min	Typ	Max	Min	Max	
V <sub>IH</sub>	High-Level Input Voltage, Select Inputs	V <sub>CC</sub> = 1.65~5.5	1.65	0.9			1.0	V
			3.3	1.6			1.7	
			5.5	2.2			2.3	
V <sub>IL</sub>	Low-Level Input Voltage, Select Inputs	V <sub>CC</sub> = 1.65~5.5	1.65			0.4	0.35	V
			3.3			0.5	0.45	
			5.5			0.6	0.55	
I <sub>IN</sub>	Maximum Input Leakage Current, Select Inputs	V <sub>IN</sub> =V <sub>CC</sub> or GND V <sub>CC</sub> =5.5V				±0.3	±1.0	uA
I <sub>OFF</sub>	Power Off Leakage Current	V <sub>IN</sub> =5.5V V <sub>CC</sub> =0V				±0.5	±1.0	uA
I <sub>CC</sub>	Maximum Quiescent Supply Current <sup>(4)</sup>	V <sub>CC</sub> =5.5V, I <sub>OUT</sub> =0 V <sub>IN</sub> = V <sub>CC</sub> or GND				±0.5	±1.0	uA
I <sub>CC</sub> T	Increase in I <sub>CC</sub> per Input	IN1=2.6V, IN2=0V, or IN2=2.6V, IN1=0V, V <sub>CC</sub> =4.3V		1.5	3.0		10	uA
		IN1=1.8V, IN2=0V, or IN2=1.8V, IN1=0V, V <sub>CC</sub> =4.3V		4.5	7.0		20	
I <sub>COM(ON)</sub>	COM ON leakage Current <sup>(5)</sup>	V <sub>IN</sub> = V <sub>IL</sub> or V <sub>IH</sub> , V <sub>NO</sub> =0.3V or 4.7V V <sub>NC</sub> floating V <sub>NC</sub> =0.3V or 4.7V V <sub>NO</sub> floating V <sub>COM</sub> =0.3V or 4.7V V <sub>CC</sub> =5.5V	-20		20		-100 100	nA
R <sub>ON</sub>	On-Resistance <sup>(4) (5)</sup>	I <sub>COM</sub> = 20mA V <sub>IS</sub> =-0.5V~0.5V, V <sub>CC</sub> =4.3V		0.5	0.8		1	Ω
		I <sub>COM</sub> = 20mA, V <sub>IS</sub> =-0.5V~0.5V, V <sub>CC</sub> =3.3V		0.6	0.9		1.1	
R <sub>FLAT</sub>	On-Resistance Flatness <sup>(4) (5) (7)</sup>	I <sub>COM</sub> =20mA V <sub>IS</sub> =-0.5V~0.5V, V <sub>CC</sub> =4.3V			0.2		0.3	Ω
ΔR <sub>ON</sub>	On-Resistance Match Between Channels <sup>(4) (5) (6)</sup>	I <sub>COM</sub> =20mA V <sub>IS</sub> =0.5V V <sub>CC</sub> =4.3V		0.1	0.2		0.3	Ω

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## Electrical Characteristics (Continued)

Symbol	Parameter	Test Conditions	T <sub>A</sub> =25°C			T <sub>A</sub> =-40~125°C		Unit
			Min	Typ	Max	Min	Max	
t <sub>ON</sub>	Turn-On Time <sup>(4)</sup> (Figure 1)	V <sub>IS</sub> =0.5V, V <sub>CC</sub> =2.5~3.3V		35	55			ns
		V <sub>IS</sub> =0.5V, V <sub>CC</sub> =3.3~5.5V		25	45			
t <sub>OFF</sub>	Turn-Off Time <sup>(4)</sup> (Figure 1)	V <sub>IS</sub> =0.5V, V <sub>CC</sub> =2.5~3.3V		26	50			ns
		V <sub>IS</sub> =0.5V, V <sub>CC</sub> =3.3~5.5V		20	40			
t <sub>BBM</sub>	Break-Before-Make Time <sup>(4)</sup> (Figure 2)	C <sub>L</sub> =35pF, R <sub>L</sub> =50Ω V <sub>IS</sub> =0.5V, V <sub>CC</sub> =2.5~3.3V		15		7		ns
		C <sub>L</sub> =35pF, R <sub>L</sub> =50Ω V <sub>IS</sub> =0.5V, V <sub>CC</sub> =3.3~5.5V		7		3		
BW	On-Channel -3dB Bandwidth or Frequency Response <sup>(4)</sup> (Figure 4)	R <sub>IS</sub> =50Ω		65				MHz
V <sub>ISO</sub>	Off-Channel Isolation <sup>(4)</sup> (Figure 5)	F <sub>IS</sub> = 100kHz, V <sub>IN</sub> =GND to V <sub>CC</sub> C <sub>L</sub> =5pF, R <sub>L</sub> = 50Ω V <sub>IS</sub> =1V V <sub>PP</sub>		-65				dB
Q	Charge Injection Select Input to Common I/O <sup>(4)</sup> (Figure 3)	V <sub>IN</sub> = 0 or V <sub>CC</sub> R <sub>IS</sub> =0Ω,C <sub>L</sub> =100pF R <sub>L</sub> =1MΩ Q=C <sub>L</sub> ×ΔV <sub>OUT</sub>		25				pC
THD	Total Harmonic Distortion THD +Noise <sup>(4)</sup>	F <sub>IS</sub> =20Hz to 20KHz R <sub>L</sub> =50Ω,C <sub>L</sub> =5pF V <sub>IS</sub> =2V RMS V <sub>CC</sub> =3.6V		0.06				%
		F <sub>IS</sub> =20Hz to 20KHz R <sub>L</sub> =50Ω,C <sub>L</sub> =5pF V <sub>IS</sub> =2V RMS V <sub>CC</sub> =5V		0.03				%
V <sub>CT</sub>	Channel-to-Channel Crosstalk <sup>(4)</sup> (Figure 6)	F <sub>IS</sub> = 100KHz, V <sub>IN</sub> =GND to V <sub>CC</sub> R <sub>L</sub> = 50Ω,C <sub>L</sub> =5pF V <sub>IS</sub> =1V V <sub>PP</sub>		-90				dB

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## Electrical Characteristics (Continued)

Symbol	Parameter	Test Conditions	T <sub>A</sub> =25°C			T <sub>A</sub> =-40~125°C		Unit
			Min	Typ	Max	Min	Max	
C <sub>IN</sub>	Control Pin Input Capacitance <sup>(4)</sup>	V <sub>CC</sub> = 3.6V		4.5				pF
C <sub>NC/CNO</sub>	NC/NO Port Capacitance <sup>(4)</sup>	V <sub>CC</sub> = 3.6V		20.0				pF
C <sub>COM</sub>	COM Port Capacitance When Switch is Enabled <sup>(4)</sup>	V <sub>CC</sub> = 3.6V		80.0				pF

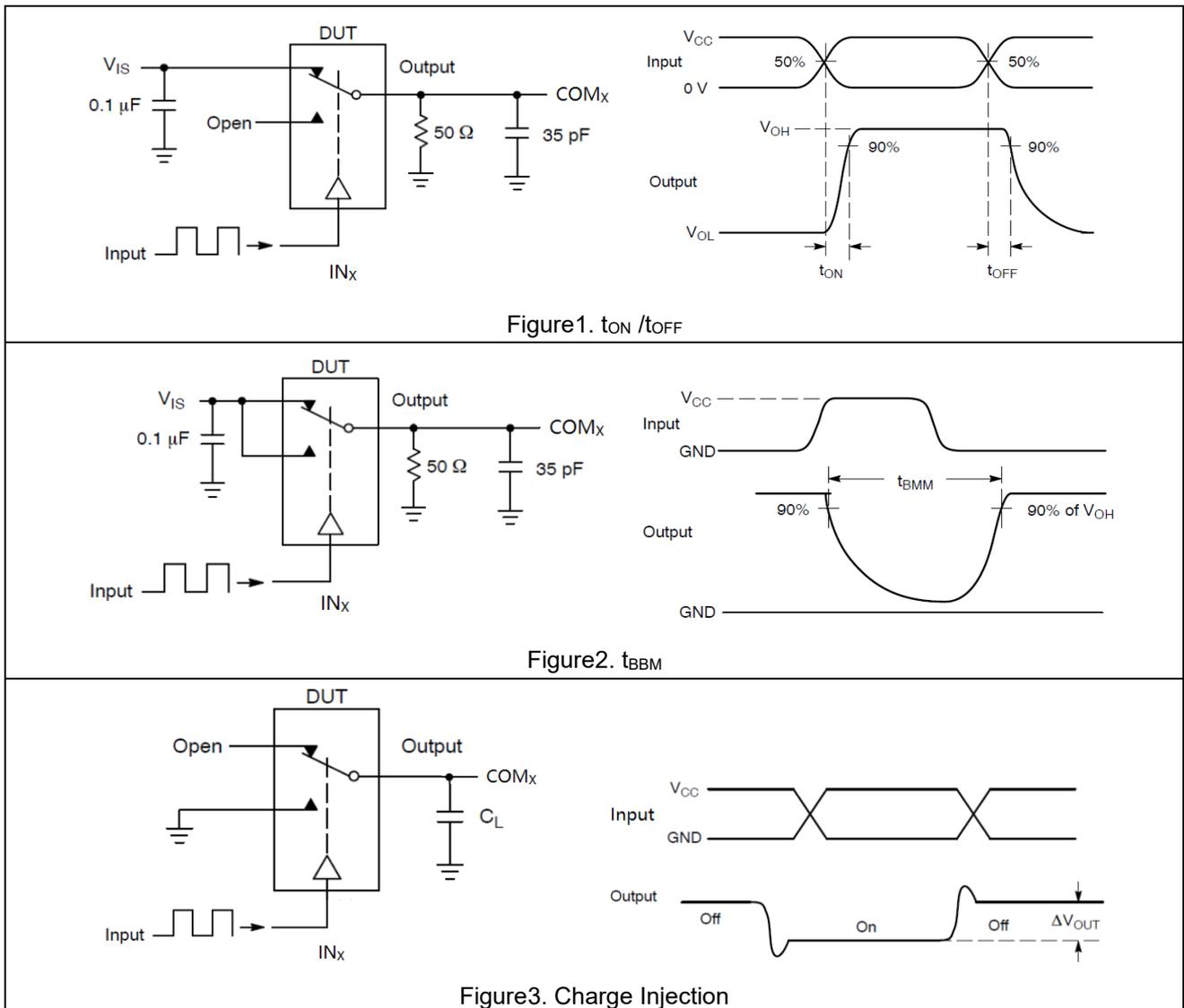
**Note4.** Guaranteed by design

**Note5.** Guaranteed by design. Resistance measurements do not include test circuit or package resistance

**Note6.**  $\Delta R_{ON} = R_{ON(NC1)} - R_{ON(NC2)}$  or  $R_{ON(NO1)} - R_{ON(NO2)}$  when V<sub>IS</sub> is same.

**Note7.** Flatness is defined as the difference between the maximum and minimum value of on-resistance as measured over the specified analog signal ranges.

## Test Circuit



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## Test Circuit (Continued)

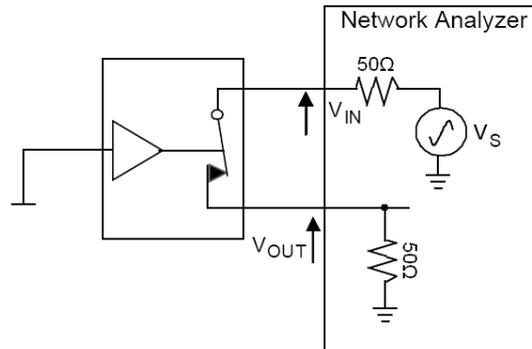
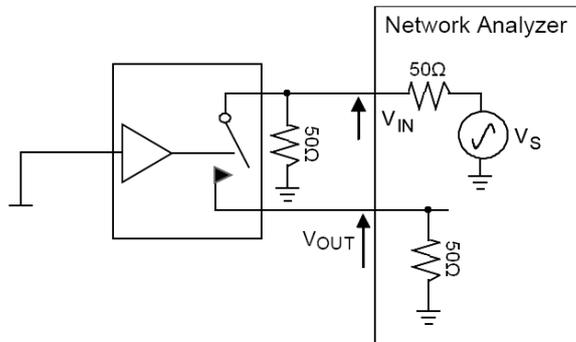
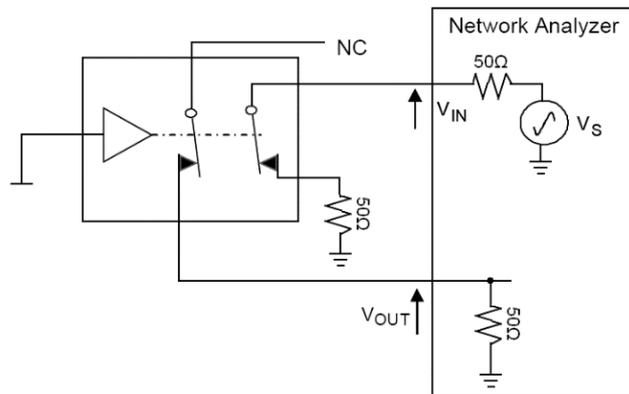


Figure4. Bandwidth



$$\text{Off-Isolation} = 20 \text{ Log } (V_{OUT} / V_{IN} )$$

Figure5. Channel Off Isolation



$$\text{CROSSTALK} = 20 \text{ Log } (V_{OUT} / V_{IN} )$$

Figure6. Non-Adjacent Channel-to-Channel Crosstalk

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## Package Dimension

QFN10L

